

RJK60S3DPP-E0

600V - 12A - SJ MOS FET High Speed Power Switching

R07DS0637EJ0300 Rev.3.00 Oct 12, 2012

Features

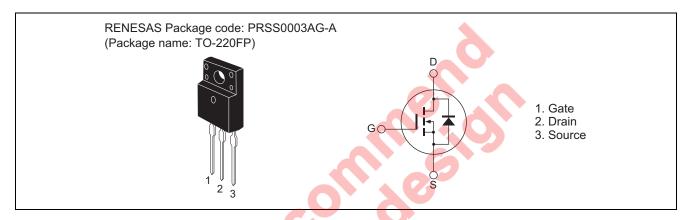
- Superjunction MOSFET
- Low on-resistance

 $R_{DS(on)} = 0.35~\Omega$ typ. (at $I_D = 6~A,~V_{GS} = 10~V,~Ta = 25^{\circ}C)$

• High speed switching

 t_f = 21 ns typ. (at I_D = 6 A, V_{GS} = 10 V, R_L = 50 Ω , Rg = 10 Ω , Ta = 25°C)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Drain to source voltage		V _{DSS}	600	V
Gate to source voltage		V _{GSS}	+30, -20	V
Drain current	Tc = 25°C	I _D Note1,2	12.0	A
	Tc = 100°C	I _D Note1,2	7.6	A
Drain peak current		I _{D (pulse)} Note1	24	A
Body-drain diode reverse drain current		I _{DR} Note1 12		Α
Body-drain diode reverse drain peak current		I _{DR (pulse)} Note1	24	Α
Avalanche current		I _{AP} Note3	3	Α
Avalanche energy		E _{AR} Note3	0.49	mJ
Channel dissipation		Pch Note4	27.7	W
Channel to case thermal impedance		θch-c	4.5	°C/W
Channel temperature		Tch	150	°C
Storage temperature	_	Tstg	-55 to +150	°C

Notes: 1. Limited by Tch max.

- 2. Maximum duty cycle D = 0.75
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C
- 4. Value at Tc = 25°C

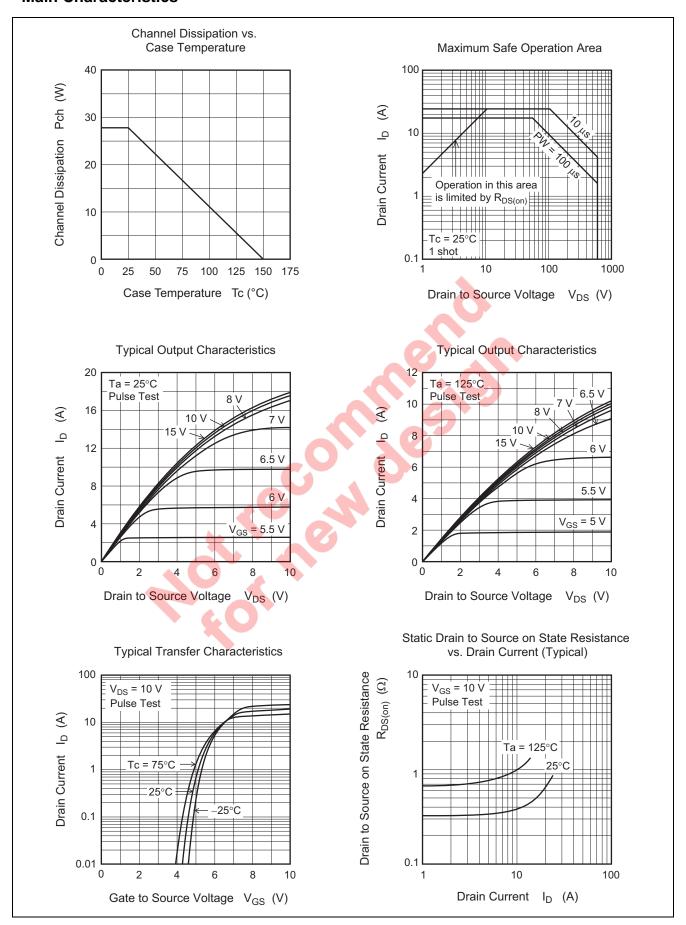
Electrical Characteristics

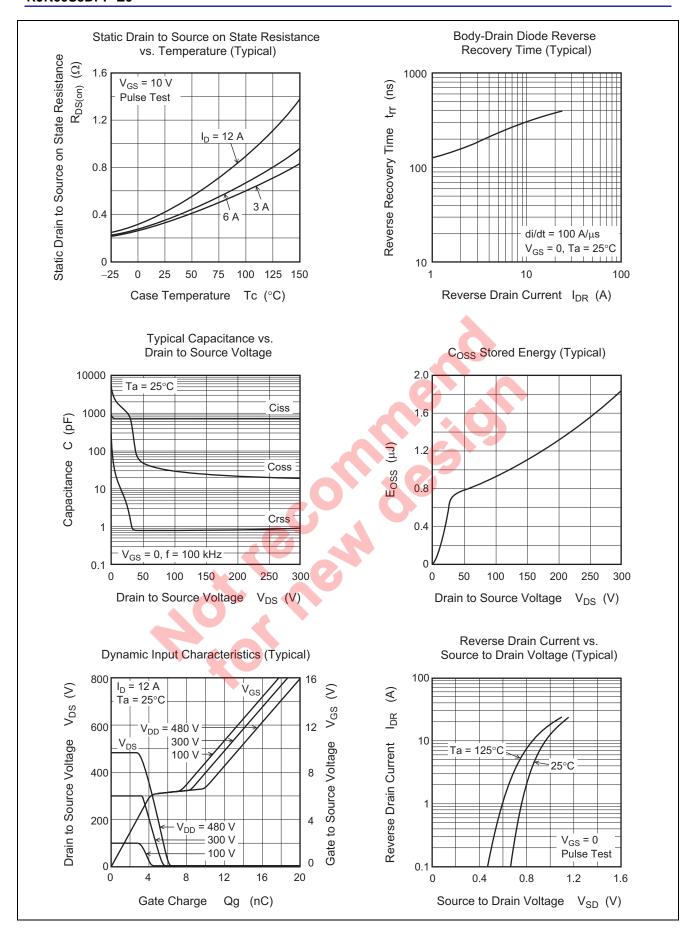
 $(Ta = 25^{\circ}C)$

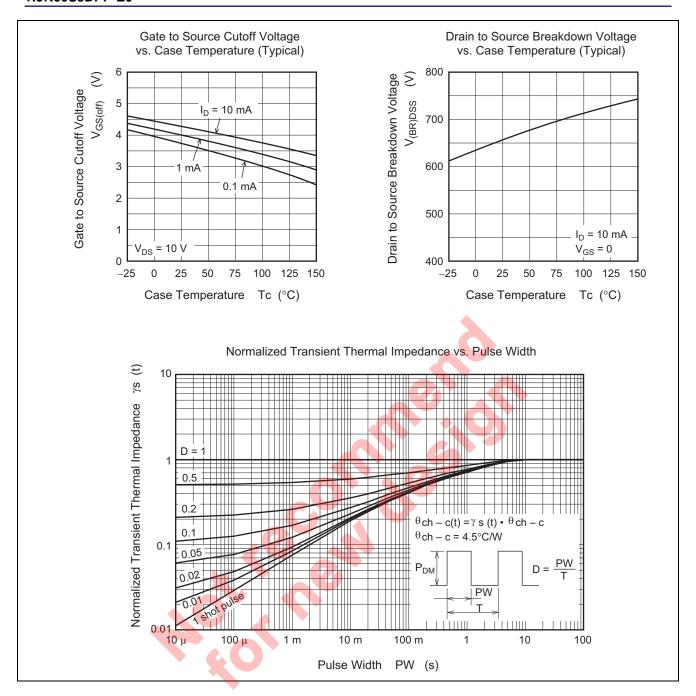
Item	Symbol	Min	Тур	Max	Unit	Test conditions		
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$		
Zero gate voltage drain current	I _{DSS}	_	_	1	mA	$V_{DS} = 600 \text{ V}, V_{GS} = 0$		
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = +30V, -20 V, V_{DS} = 0$		
Gate to source cutoff voltage	V _{GS(off)}	3	_	5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$		
Static drain to source on state	R _{DS(on)}		0.35	0.44	Ω	$I_D = 6 \text{ A}, V_{GS} = 10 \text{ V}^{Note5}$		
resistance	R _{DS(on)}		0.87	_	Ω	Ta = 150°C $I_D = 6 \text{ A}, V_{GS} = 10 \text{ V}^{Note5}$		
Gate resistance	Rg	_	2.5	_	Ω	f = 1 MHz V _{DS} = 25 V, V _{GS} = 0		
Input capacitance	Ciss	_	720	_	pF	V _{DS} = 25 V		
Output capacitance	Coss	_	980	_	pF	$V_{GS} = 0$		
Reverse transfer capacitance	Crss	_	3.7	_	pF	f = 100 kHz		
Turn-on delay time	t _{d(on)}	_	13	_	ns	I _D = 6 A		
Rise time	t _r	_	18		ns	V _{GS} = 10 V		
Turn-off delay time	t _{d(off)}	_	25	_	ns	$R_L = 50 \Omega$		
Fall time	t _f		18	}	ns	$Rg = 10 \Omega^{Note5}$		
Total gate charge	Qg		13.6		nC	V _{DD} = 480 V		
Gate to source charge	Qgs	_	4.8		nC	$V_{GS} = 10 \text{ V}$		
Gate to drain charge	Qgd		3.9		nC	$I_D = 12 \text{ A}^{\text{Note5}}$		
Body-drain diode forward voltage	V_{DF}	_	1.0	1.6	V	$I_F = 12 \text{ A}, V_{GS} = 0^{\text{Note5}}$		
Body-drain diode reverse recovery time	t _{rr}	_	320	62	ns	I _F = 12 A		
Body-drain diode reverse recovery current	I _{rr}	5	20	3	А	$V_{GS} = 0$ $di_F/dt = 100 \text{ A/}\mu\text{s}^{\text{Note5}}$		
Body-drain diode reverse recovery charge	Qrr		3.7	_	μС			
Notes: 5. Pulse test		0						

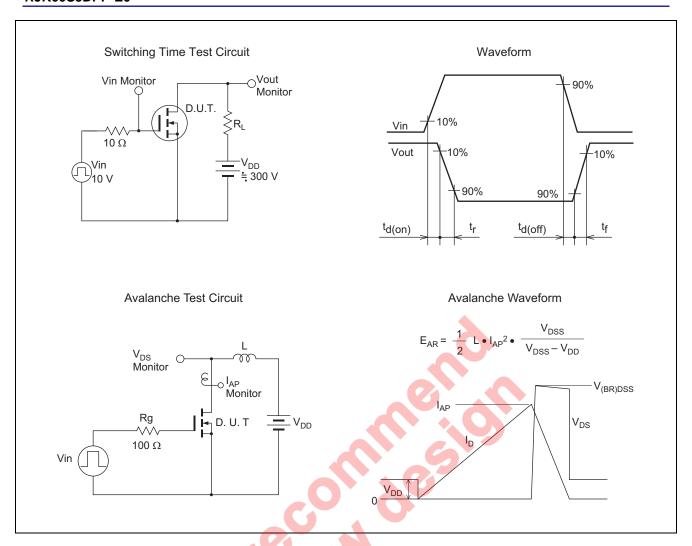
Notes: 5. Pulse test

Main Characteristics

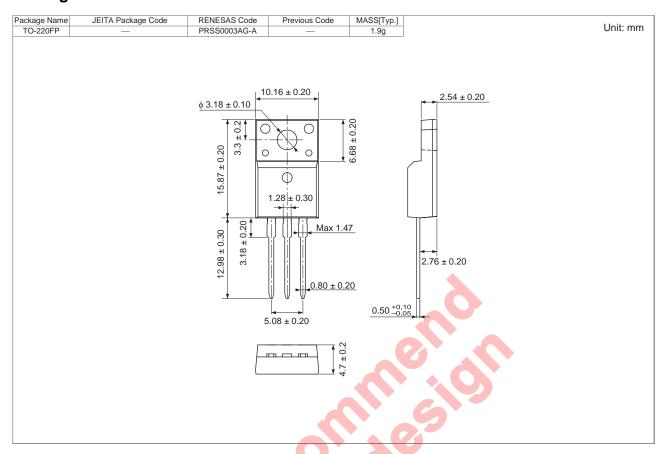








Package Dimension



Ordering Information

Orderable Part Number		Q	uantity		Shipping Container
RJK60S3DPP-E0#T2	1000 pcs			E	Box (Tube)

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